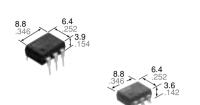






Greatly increase load current (2.5A). Load voltage is 60V.

HE PhotoMOS (AQV252G)



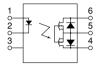
FEATURES

- 1. Greatly increased load current in the same package size.
- 2. Greatly improved specs allow you to use this in place of mercury and mechanical relays.

TYPICAL APPLICATIONS

- Crime and fire prevention market (use in I/O for alarm and security devices, etc.)
- · Measuring instrument market (circuit testers, etc.)

mm inch



TYPES

Туре	Output rating*			Par	Packing quantity			
			Through hole terminal	Surface-mount terminal				
	Load voltage	Load current			Tape and reel packing style			1
			Tube pac	king style	Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC type	60 V	2.5 A	AQV252G	AQV252GA	AQV252GAX	AQV252GAZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Symbol	Type of connection	AQV252G(A)	Remarks		
	LED forward current	lF		50 mA		
loout	LED reverse voltage	VR		5 V		
Input	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
	Load voltage (peak AC)	VL		60 V		
		L	Α	2.5 A	A connection: Peak AC, DC B, C connection: DC	
Outout	Continuous load current (peak AC)		В	3.5 A		
Output	(peak AO)		С	5.0 A	B, C connection. BC	
	Peak load current	Ipeak		6.0 A	100ms (1 shot), V _L = DC	
	Power dissipation	Pout		500 mW		
Total power dissipation		P⊤		550 mW		
I/O isolation voltage		Viso		1,500 V AC		
Temperature limits	Operating	Topr		−40°C to +85°C −40°F to +185°F	Non-condensing at low temperatures	
	Storage	T _{stg}		-40°C to +100°C -40°F to +212°F		

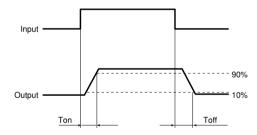
HE PhotoMOS (AQV252G)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

		Symbol	Type of connection	AQV252G(A)	Condition		
Input	LED operate	Typical	Fon	_	0.5 mA	- IL = 100mA	
	current	Maximum	IFON		3 mA		
	LED turn off	Minimum	Foff	_	0.2 mA	lı = 100mA	
	current	Typical			0.45 mA	IL = TOUTIA	
	LED dropout voltage	Typical	VF		1.32 V (1.14 V at I _F = 5 mA)	I _F = 50 mA	
		Maximum			1.5 V	7 IF = 50 IIIA	
Output	On resistance	Typical	Ron	Α	0.08 Ω		
		Maximum			0.12 Ω		
		Typical	Ron	В	0.04 Ω	│ IF = 5 mA │ IL = Max.	
		Maximum			0.06 Ω	Within 1 s on time	
Cutput		Typical	Ron	С	0.02 Ω		
		Maximum			0.03 Ω		
	Off state leakage current	Maximum	Leak	_	1 μΑ	IF = 0 mA VL = Max.	
Transfer characteristics		Typical	Ton	_	1.1 ms	I _F = 5 mA	
	Turn on time*	Maximum			5.0 ms	I _L = 100 mA V _L = 10 V	
	Turn off time*	Typical	Toff	_	0.25 ms	I _F = 5 mA I _L = 100 mA	
	lum on time	Maximum			0.5 ms	V _L = 10 V	
	I/O conscitones	Typical	Ciso	_	0.8 pF	f = 1 MHz	
	I/O capacitance	Maximum			1.5 pF	V _B = 0 V	
	Initial I/O isolation resistance	Minimum	Riso	_	1,000 ΜΩ	500 V DC	

Note: Recommendable LED forward current I_F = 5 to 10 mA.

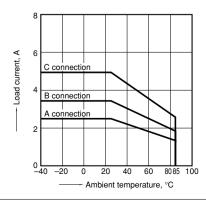
*Turn on/Turn off time



REFERENCE DATA

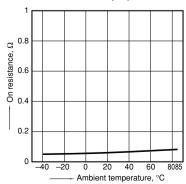
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$ -40°F to $+185^{\circ}\text{F}$



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)

